1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DS}	+25V
V _{GS}	+10.0V / -8V
I _{D,} Continuous	60A, T _C = 25°C
P _D	1.8W, T _A = +25°C
T _J , T _{STG}	55°C to +150°C
E _{AS} Avalanche Energy	162 mJ

DC ELECTRICAL CHARACTERISTICS

 I_D = 18A, L = 1 mH, R_G = 25 Ω

† Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

Electrical Characteristics: Unless	otherwise i	ndicated	, T _A = +2	5°C		
Parameters	Sym	Min	Тур	Max	Units	Conditions
Static Characteristics						
Drain-to-Source Breakdown Voltage	B _{VDSS}	25	_	_	V	V _{GS} = 0V, I _D = 250 μA
Drain-to-Source Leakage Current	I _{DSS}			1	μA	V _{GS} = 0V, V _{DS} = 20V
Gate-to-Source Leakage Current	I _{GSS}	_		100	nA	V _{DS} = 0V, V _{GS} = 10V/-8V
Gate-to-Source Threshold Voltage	V _{GS(TH)}	1.1	1.35	1.7	V	V _{DS} = V _{GS} , I _D = 250 μA
Drain-to-Source On Resistance	R _{DS(ON)}	_	5.7	7	mΩ	V _{GS} = 4.5V, I _D = 20A
	. ,	_	4.7	6	mΩ	V _{GS} = 10V, I _D = 20A
Transconductance	9 _{fs}		92		S	V _{DS} = 12.5V, I _D = 20A
Dynamic Characteristics						
Input Capacitance	C _{ISS}	_	890		pF	V _{GS} = 0V, V _{DS} = 12.5V, f = 1 MHz
Output Capacitance	C _{OSS}		420	_	pF	V _{GS} = 0V, V _{DS} = 12.5V, f = 1 MHz
Reverse Transfer Capacitance	C _{RSS}		114	_	pF	V _{GS} = 0V, V _{DS} = 12.5V, f = 1 MHz
Total Gate Charge	Q _G	_	11	14	nC	V _{DS} = 12.5V, I _D = 20A, V _{GS} = 4.5
Gate-to-Drain Charge	Q _{GD}		4.5	_	nC	V _{DS} = 12.5V, I _D = 20A
Gate-to-Source Charge	Q _{GS}		1.8	_	nC	V _{DS} = 12.5V, I _D = 20A
Gate Charge at VTH	Q _{G(TH)}	_	1.1	_	nC	V _{DS} = 12.5V, I _D = 20A
Output Charge	Q _{OSS}		8	_	nC	V _{DS} = 12.5V, V _{GS} = 0
Turn-On Delay Time	t _{d(on)}	_	4.5		ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω
Rise Time	t _r	_	11	_	ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω
Turn-Off Delay Time	t _{d(off)}	—	9	—	ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I _D = 20A, R _G = 2 Ω
Fall Time	t _f	—	4.6		ns	V_{DS} = 12.5V, V_{GS} = 4.5V, I_{D} = 20A, R_{G} = 2 Ω
Series Gate Resistance	R _G	_	2.1	_	Ω	

DC ELECTRICAL CHARACTERISTICS (CONTINUED)

Electrical Characteristics: Unless otherwise indicated, T _A = +25°C								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Diode Characteristics								
Diode Forward Voltage	V _{FD}	—	0.8	1	V	I _S = 20A, V _{GS} = 0V		
Reverse Recovery Charge	Q _{RR}	—	18	—	nC	I _S = 20A, di/dt = 300 A/μs		
Reverse Recovery Time	t _{rr}	—	15	—	ns	I _S = 20A, di/dt = 300 A/μs		
Avalanche Characteristics								
Avalanche Energy	E _{AS}	50	_	_	mJ	I_D = 10A, L = 1 mH, R _G = 25 Ω		
						R _G = 25Ω		

TEMPERATURE CHARACTERISTICS

Electrical Characteristics: Unless otherwise indicated, $T_A = +25^{\circ}C$						
Parameters	Sym	Min	Тур	Max	Units	Conditions
Temperature Ranges						
Operating Junction Temperature Range	Τ _J	-55		150	°C	
Storage Temperature Range	T _A	-55	_	150	°C	
Package Thermal Resistances						
Thermal Resistance Junction-to-X, 8L 3.3x3.3-PDFN	R_{\thetaJX}	_		66	°C/W	Note 1
Thermal Resistance Junction-to-Case, 8L 3.3x3.3-PDFN	$R_{\theta JC}$	_	_	3.4	°C/W	Note 2

Note 1: R_{0JX} is determined with the device surface mounted on a 4-Layer FR4 PCB, with a 1" x 1" mounting pad of 2 oz. copper. This characteristic is dependent on user's board design.

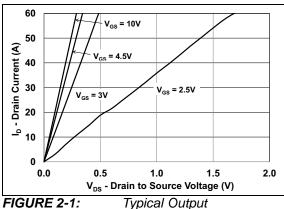
2: $R_{\theta JC}$ is determined using JEDEC 51-14 Method. This characteristic is determined by design.

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2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$.



Characteristics.

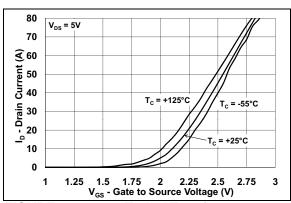


FIGURE 2-2: Typical Transfer Characteristics.

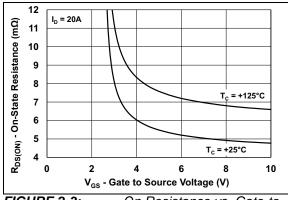
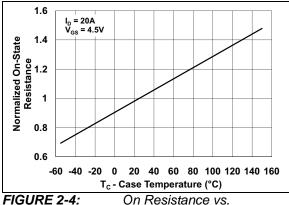


FIGURE 2-3: On Resistance vs. Gate-to-Source Voltage.







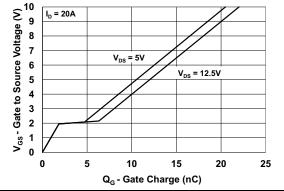
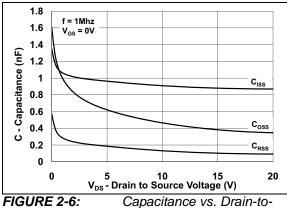
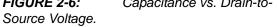
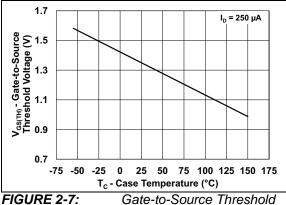


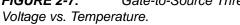
FIGURE 2-5: Gate-to-Source Voltage vs. Gate Charge.

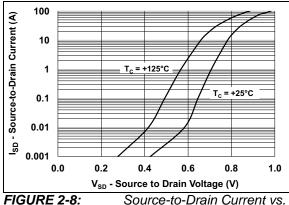




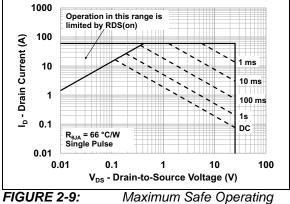
Note: Unless otherwise indicated, $T_A = +25^{\circ}C$.



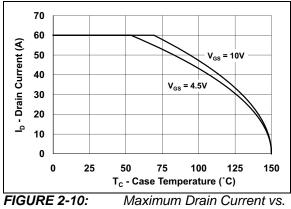




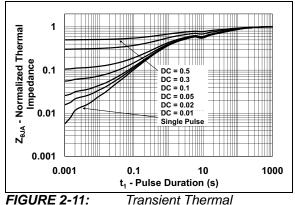
Source-to-Drain Voltage.



Area.



Temperature.



Impedance.

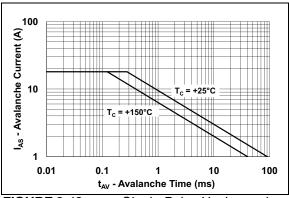
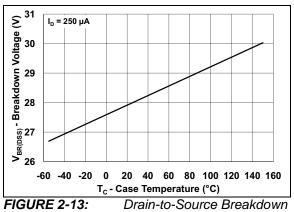


FIGURE 2-12: Single-Pulse Unclamped Inductive Switching.

MCP87055

Note: Unless otherwise indicated, $T_A = +25^{\circ}C$.



Voltage vs. Temperature.

3.0 **PIN DESCRIPTIONS**

The descriptions of the pins are listed in Table 3-1.

TABLE 3-1: PIN FUNCTION TABLE

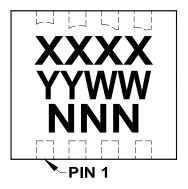
MCP87055 3 x 3 PDFN	Symbol	Description	
1, 2, 3	S	Source pin	
4	G	Gate pin	
5, 6, 7, 8	D	Drain pin, including exposed thermal pad	

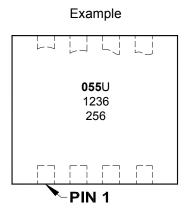
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4.0 PACKAGING INFORMATION

4.1 Package Marking Information*

8-Lead PDFN (3.3 x 3.3 x 0.9 mm)



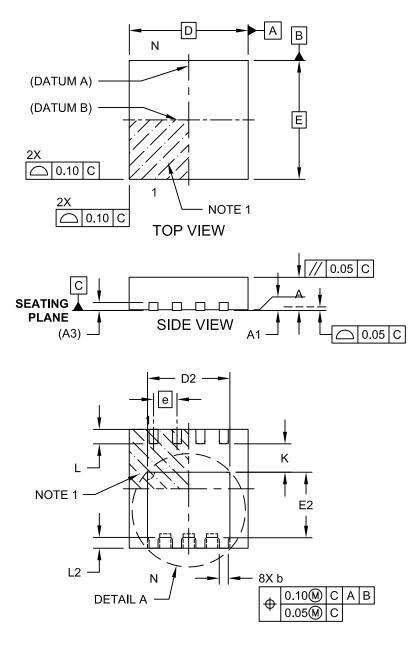


*RoHS compliant using EU-RoHS exemption: 7(a) - Lead in high-melting-temperature-type solders (i.e. lead-based alloys containing 85% by weight or more lead) can be found on the outer packaging for this package.

Legenc	I: XXX Y YY WW NNN	Customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code
Note:	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

8-Lead Power Dual Flatpack No Lead Package (LC) – 3.3x3.3x1.0 mm Body [PDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



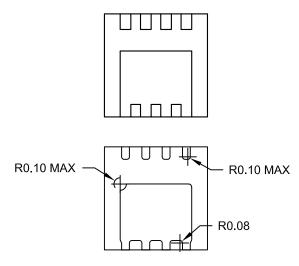
BOTTOM VIEW

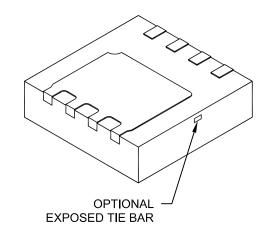
Microchip Technology Drawing C04-195A Sheet 1 of 2

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8-Lead Power Dual Flatpack No Lead Package (LC) – 3.3x3.3x1.0 mm Body [PDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





DETAIL A ALTERNATE EXPOSED PAD CONFIGURATIONS

	Units	Ν	/ILLIMETER	S
Dir	nension Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		0.65 BSC	
Overall Height	А	0.80	1.00	1.03
Standoff	A1	0.00	-	0.05
Terminal Thickness	(A3)		0.20 REF	
Overall Length	D	3.30 BSC		
Overall Width	E		3.30 BSC	
Exposed Pad length	D2	2.14	2.29	2.39
Exposed Pad Width	E2	1.66	1.81	1.91
Terminal Width	b	0.25	0.30	0.35
Terminal Length	L	0.30	0.40	0.50
Terminal Length	L2	0.30	-	0.40
Terminal to Exposed Pad	К	0.60	-	-

Notes:

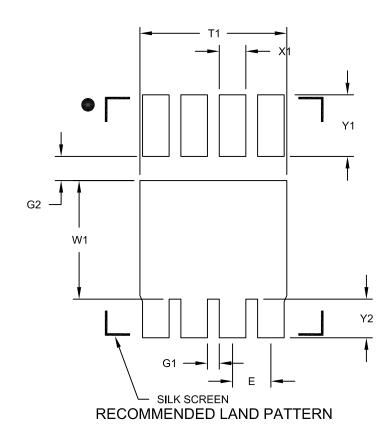
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package may have one or more exposed tie bars.
- 3. Package is saw singulated.
- 4. Package dimension does not include mold flash, protrusions, burrs or metal smearing.
- 5. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-195A Sheet 2 of 2

8-Lead Power Dual Flatpack No Lead Package (LC) - 3.3x3.3x1.0 mm Body [PDFN]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS				
Dimension	Dimension Limits			MAX	
Contact Pitch	E		0.65 BSC		
Center Pad Width	W1			2.01	
Center Pad Length	T1			2.49	
Distance Between Terminals	G1	0.20			
Terminal Edge to Center Pad	G2	0.41			
Terminal Pad Width (X8)	X1			0.45	
Terminal Pad Length (X4)	Y1			1.05	
Terminal Pad Length (X8)	Y2			0.66	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2195A

MCP87055

NOTES:

APPENDIX A: REVISION HISTORY

Revision B (November 2012)

• Updated the Gate-to-Source Charge value and the Gate Charge at VTH value in the DC Electrical Characteristics table.

Revision A (September 2012)

• Original Release of this Document.

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PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO. X /XX Device Temperature Package Range	Examples: a) MCP87055T-U/LC: Tape and Reel, Ultra-HighTemperature, 8LD DFN package
Device: MCP87055T: High Speed N-Channel Power MOSFET (Tape and Reel)	
Temperature Range: U = -55°C to +150°C (Ultra-High)	
Package: LC = Power Dual Flatpack, No Lead Package (3.3x3.3x1.0 mm Body) (DFN), 8-lead	

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